

SNx4HCT244 Octal Buffers and Line Drivers With 3-State Outputs

1 Features

- Operating voltage range of 4.5 V to 5.5 V
- High-current outputs drive up to 15 LSTTL loads
- Low power consumption: 80- μ A maximum I_{CC}
- Typical $t_{pd} = 13$ ns
- ± 6 -mA output drive at 5 V
- Low input current of 1 μ A maximum
- Inputs are TTL-voltage compatible
- 3-state outputs drive bus lines and buffer memory address registers

2 Applications

- Servers
- LED displays
- Network switches
- Telecom infrastructure
- Motor drivers
- I/O expanders

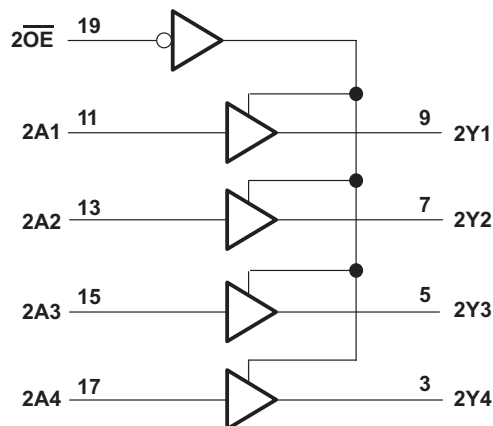
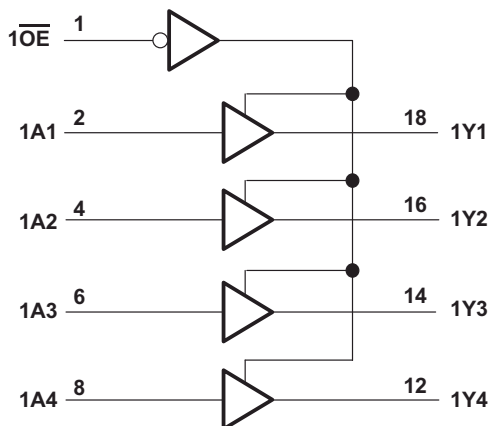
3 Description

These octal buffers and line drivers are designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented receivers and transmitters. The SNx4HCT244 devices are organized as two 4-bit buffers or drivers with separate output-enable (\overline{OE}) inputs. When \overline{OE} is low, the device passes non inverted data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state.

Device Information

| PART NUMBER | RATING | PACKAGE ⁽¹⁾ |
|-------------|----------|------------------------|
| SN74HCT244 | Catalog | DB (SSOP, 20) |
| | | DW (SOIC, 20) |
| | | N (PDIP, 20) |
| | | NS (SO, 20) |
| | | PW (TSSOP, 20) |
| | | DGS (VSSOP, 20) |
| SN54HCT244 | Military | J (CDIP, 20) |
| | | FK (LCCC, 20) |

(1) For all available packages, see the orderable addendum at the end of the data sheet.



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Logic Diagram (Positive Logic)



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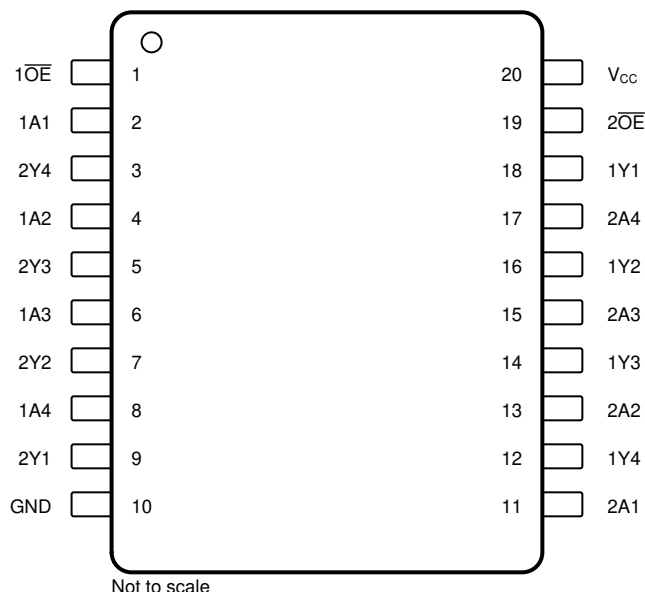
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4 Revision History

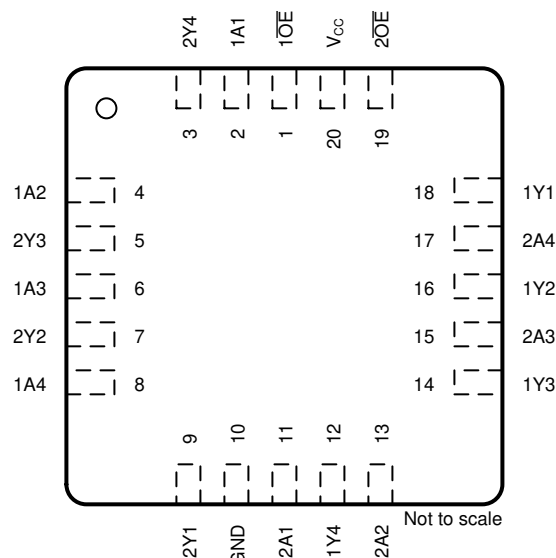
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| | |
|--|-------------|
| Changes from Revision G (December 2022) to Revision H (August 2023) | Page |
| • Added supporting information for the DGS (SOT) package..... | 1 |
| • Updated the <i>Device Information</i> table to include rating..... | 1 |
| • Removed the <i>W (CFP, 20)</i> package from the data sheet..... | 1 |
| Changes from Revision F (May 2022) to Revision G (December 2022) | Page |
| • Added DGS (SOT) package information..... | 1 |
| • Added DGS (SOT) package information..... | 3 |
| • Added DGS (SOT) package thermal information..... | 5 |
| Changes from Revision E (August 2016) to Revision F (May 2022) | Page |
| • Junction-to-ambient thermal resistance values increased. DW was 76.6 is now 109.1, DB was 89.4 is now 122.7, N was 44.8 is now 84.6, NS was 71.8 is now 113.4, PW was 97.4 is now 131.8..... | 5 |
| Changes from Revision D (August 2013) to Revision E (August 2016) | Page |
| • Added <i>ESD Ratings</i> table, <i>Feature Description</i> section, <i>Device Functional Modes</i> , <i>Application and Implementation</i> section, <i>Power Supply Recommendations</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section | 1 |
| • Deleted <i>Ordering Information</i> table; see POA at the end of the data sheet..... | 1 |
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| • Added ESD warning..... | 9 |

5 Pin Configuration and Functions



**J, DB, DW, N, NS, PW or DGS Packages, 20-Pin
CDIP, CFP, SSOP, SOIC, PDIP, SO, TSSOP, or
VSSOP (Top View)**



FK Package, 20-Pin LCCC (Top View)

Table 5-1. Pin Functions

| PIN | | TYPE ⁽¹⁾ | DESCRIPTION |
|-----------------|-----|---------------------|---------------|
| NAME | NO. | | |
| 1 OE | 1 | I | Output enable |
| 1A1 | 2 | I | Input |
| 2Y4 | 3 | O | Output |
| 1A2 | 4 | I | Input |
| 2Y3 | 5 | O | Output |
| 1A3 | 6 | I | Input |
| 2Y2 | 7 | O | Output |
| 1A4 | 8 | I | Input |
| 2Y1 | 9 | O | Output |
| GND | 10 | — | Ground |
| 2A1 | 11 | I | Input |
| 1Y4 | 12 | O | Output |
| 2A2 | 13 | I | Input |
| 1Y3 | 14 | O | Output |
| 2A3 | 15 | I | Input |
| 1Y2 | 16 | O | Output |
| 2A4 | 17 | I | Input |
| 1Y1 | 18 | O | Output |
| 2 OE | 19 | I | Output enable |
| V _{CC} | 20 | — | Power pin |

(1) Signal Types: I = Input, O = Output, I/O = Input or Output.

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

| | | MIN | MAX | UNIT |
|------------------|---|--|-----|--------|
| V _{CC} | Supply voltage | −0.5 | 7 | V |
| I _{IK} | Input clamp current ⁽²⁾ | V _I < 0 or V _I > V _{CC} | | ±20 mA |
| I _{OK} | Output clamp current ⁽²⁾ | V _O < 0 or V _O > V _{CC} | | ±20 mA |
| I _O | Continuous output current | V _O = 0 to V _{CC} | | ±35 mA |
| | Continuous channel current through V _{CC} or GND | | | ±70 mA |
| T _J | Junction temperature | | | 150 °C |
| T _{stg} | Storage temperature | −65 | 150 | °C |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- (2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

6.2 ESD Ratings

| | | | VALUE | UNIT |
|--|-------------------------|--|-------|------|
| SN74HCT244 in DB, DW, N, NS, or PW package | | | | |
| V _(ESD) | Electrostatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾ | ±2000 | V |
| | | Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾ | ±1000 | |
| SN54HCT244 in J or FK package | | | | |
| V _(ESD) | Electrostatic discharge | Human-body model (HBM) | ±1500 | V |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

| | | MIN | NOM | MAX | UNIT |
|-----------------|-------------------------------------|----------------------------------|-----------------|-----|------|
| V _{CC} | Supply voltage | 4.5 | 5 | 5.5 | V |
| V _{IH} | High-level input voltage | V _{CC} = 4.5 V to 5.5 V | | 2 | V |
| V _{IL} | Low-level input voltage | V _{CC} = 4.5 V to 5.5 V | | 0.8 | V |
| V _I | Input voltage | 0 | V _{CC} | | V |
| V _O | Output voltage | 0 | V _{CC} | | V |
| Δt/Δv | Input transition rise and fall time | | | 500 | ns |
| T _A | Operating free-air temperature | SN54HCT244 | | −55 | °C |
| | | | | 125 | |
| | | SN74HCT244 ⁽²⁾ | | −40 | |
| | | | | 85 | |
| | | | | 125 | |

- (1) All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. See the [Implications of Slow or Floating CMOS Inputs](#) application report.

- (2) For correct operating free-air temperature, see the orderable addendum at the end of the data sheet.

6.4 Thermal Information

| THERMAL METRIC | | SN74HCT244 | | | | | | UNIT |
|-----------------------|---|------------|-----------|----------|---------|------------|-------------|------|
| | | DW (SOIC) | DB (SSOP) | N (PDIP) | NS (SO) | PW (TSSOP) | DGS (VSSOP) | |
| | | 20 PINS | 20 PINS | 20 PINS | 20 PINS | 20 PINS | 20 PINS | |
| $R_{\theta JA}$ | Junction-to-ambient thermal resistance ⁽¹⁾ | 109.1 | 122.7 | 84.6 | 113.4 | 131.8 | 130.6 | °C/W |
| $R_{\theta JC (top)}$ | Junction-to-case (top) thermal resistance | 76 | 81.6 | 72.5 | 78.6 | 72.2 | 68.7 | °C/W |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | 77.6 | 77.5 | 65.3 | 78.4 | 82.8 | 85.4 | °C/W |
| Ψ_{JT} | Junction-to-top characterization parameter | 51.5 | 46.1 | 55.3 | 47.1 | 21.5 | 10.5 | °C/W |
| Ψ_{JB} | Junction-to-board characterization parameter | 77.1 | 77.1 | 65.2 | 78.1 | 82.4 | 85.0 | °C/W |
| $R_{\theta JC (bot)}$ | Junction-to-case (bottom) thermal resistance | N/A | N/A | N/A | N/A | N/A | N/A | °C/W |

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

6.5 Electrical Characteristics - SN54HCT244

over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | | V_{CC} | $T_A = 25^\circ\text{C}$ | | | $-55^\circ\text{C to } 125^\circ\text{C}$ | | | UNIT |
|--------------------------------|---|--|----------------|--------------------------|------------|-----------|---|-----|------------|---------------|
| | | | | MIN | TYP | MAX | MIN | TYP | MAX | |
| V_{OH} | $V_I = V_{IH} \text{ or } V_{IL}$ | $I_{OH} = -20 \mu\text{A}$ $I_{OH} = -6 \text{ mA}$ | 4.5 V | 4.4 | 4.499 | | 4.4 | | | V |
| V_{OL} | $V_I = V_{IH} \text{ or } V_{IL}$ | $I_{OL} = 20 \mu\text{A}$ $I_{OL} = 6 \text{ mA}$ | 4.5 V | | 0.001 | 0.1 | | | 0.1 | V |
| | | | | | 0.17 | 0.26 | | | 0.4 | |
| I_I | $V_I = V_{CC} \text{ or } 0$ | | 5.5 V | | ± 0.1 | ± 100 | | | ± 1000 | nA |
| I_{OZ} | $V_O = V_{CC} \text{ or } 0, V_I = V_{IH} \text{ or } V_{IL}$ | | 5.5 V | | ± 0.01 | ± 0.5 | | | ± 10 | μA |
| I_{CC} | $V_I = V_{CC} \text{ or } 0, I_O = 0$ | | 5.5 V | | | 8 | | | 160 | μA |
| ΔI_{CC} ⁽¹⁾ | One input at 0.5 V or 2.4 V, Other inputs at 0 or V_{CC} | | 5.5 V | | 1.4 | 2.4 | | | 3 | mA |
| C_i | | | 4.5 V to 5.5 V | | 3 | 10 | | | 10 | pF |

(1) This is the increase in supply current for each input that is at one of the specified TTL voltage levels, rather than 0 V or V_{CC} .

6.6 Electrical Characteristics - SN74HCT244

over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER | TEST CONDITIONS | | V _{CC} | T _A = 25°C | | | -40°C to 85°C | | | -40°C to 125°C | | | UNIT |
|---------------------------------|--|--------------------------|-----------------|-----------------------|-------|-----|---------------|-------|-----|----------------|-------|-----|------|
| | | | | MIN | TYP | MAX | MIN | TYP | MAX | MIN | TYP | MAX | |
| V _{OH} | V _I = V _{IH} or V _{IL} | I _{OH} = -20 μA | 4.5 V | 4.4 | 4.499 | | 4.4 | | | 4.4 | | | V |
| | | I _{OH} = -6 mA | | 3.98 | 4.3 | | 3.84 | | | 3.7 | | | |
| V _{OL} | V _I = V _{IH} or V _{IL} | I _{OL} = 20 μA | 4.5 V | 0.001 | 0.1 | | | | | | | 0.1 | V |
| | | I _{OL} = 6 mA | | 0.17 | 0.26 | | 0.33 | | | 0.4 | | | |
| I _I | V _I = V _{CC} or 0 | | 5.5 V | ±0.1 | ±100 | | | ±1000 | | | ±1000 | | nA |
| I _{OZ} | V _O = V _{CC} or 0, V _I = V _{IH} or V _{IL} | | 5.5 V | ±0.01 | ±0.5 | | | ±5 | | | ±10 | | μA |
| I _{CC} | V _I = V _{CC} or 0, I _O = 0 | | 5.5 V | | 8 | | | 80 | | | 160 | | μA |
| ΔI _{CC} ⁽¹⁾ | One input at 0.5 V or 2.4 V, Other inputs at 0 or V _{CC} | | 5.5 V | 1.4 | 2.4 | | | 2.9 | | | 3 | | mA |
| C _i | | | 4.5 V to 5.5 V | 3 | 10 | | | 10 | | | 10 | | pF |

(1) This is the increase in supply current for each input that is at one of the specified TTL voltage levels, rather than 0 V or V_{CC}.

6.7 Switching Characteristics: SN54HCT244

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 7-1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | V _{CC} | LOAD CAPACITANCE | T _A = 25°C | | | -55°C to 125°C | | UNIT |
|------------------|-----------------|----------------|-----------------|-------------------------|-----------------------|-----|-----|----------------|-----|------|
| | | | | | MIN | TYP | MAX | MIN | MAX | |
| t _{pd} | A | Y | 4.5 V | C _L = 50 pF | | 15 | 28 | | 42 | ns |
| | | | | C _L = 150 pF | | 21 | 45 | | 68 | |
| | | | 5.5 V | C _L = 50 pF | | 13 | 25 | | 38 | |
| | | | | C _L = 150 pF | | 18 | 40 | | 61 | |
| t _{en} | OE | Y | 4.5 V | C _L = 50 pF | | 21 | 35 | | 53 | ns |
| | | | | C _L = 150 pF | | 25 | 52 | | 79 | |
| | | | 5.5 V | C _L = 50 pF | | 19 | 32 | | 48 | |
| | | | | C _L = 150 pF | | 22 | 47 | | 71 | |
| t _{dis} | OE | Y | 4.5 V | C _L = 50 pF | | 19 | 35 | | 53 | ns |
| | | | 5.5 V | C _L = 50 pF | | 18 | 32 | | 48 | |
| t _t | | Y | 4.5 V | C _L = 50 pF | | 8 | 12 | | 18 | ns |
| | | | | C _L = 150 pF | | 17 | 42 | | 63 | |
| | | | 5.5 V | C _L = 50 pF | | 7 | 11 | | 16 | |
| | | | | C _L = 150 pF | | 14 | 38 | | 57 | |

6.8 Switching Characteristics: SN74HCT244

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 7-1)

| PARAMETER | FROM (INPUT) | TO (OUTPUT) | V _{CC} | LOAD CAPACITANCE | T _A = 25°C | | | -40°C to 85°C | | -40°C to 125°C | | UNIT |
|------------------|-----------------|----------------|-----------------|-------------------------|-----------------------|-----|-----|---------------|-----|----------------|-----|------|
| | | | | | MIN | TYP | MAX | MIN | MAX | MIN | MAX | |
| t _{pd} | A | Y | 4.5 V | C _L = 50 pF | | 15 | 28 | | 35 | | 42 | ns |
| | | | | C _L = 150 pF | | 21 | 45 | | 56 | | 68 | |
| | | | 5.5 V | C _L = 50 pF | | 13 | 25 | | 32 | | 38 | |
| | | | | C _L = 150 pF | | 18 | 40 | | 51 | | 61 | |
| t _{en} | OE | Y | 4.5 V | C _L = 50 pF | | 21 | 35 | | 44 | | 53 | ns |
| | | | | C _L = 150 pF | | 25 | 52 | | 65 | | 79 | |
| | | | 5.5 V | C _L = 50 pF | | 19 | 32 | | 40 | | 48 | |
| | | | | C _L = 150 pF | | 22 | 47 | | 59 | | 71 | |
| t _{dis} | OE | Y | 4.5 V | C _L = 50 pF | | 19 | 35 | | 44 | | 53 | ns |
| | | | 5.5 V | | | 18 | 32 | | 40 | | 48 | |
| t _t | | Y | 4.5 V | C _L = 50 pF | | 8 | 12 | | 15 | | 18 | ns |
| | | | | C _L = 150 pF | | 17 | 42 | | 53 | | 63 | |
| | | | 5.5 V | C _L = 50 pF | | 7 | 11 | | 14 | | 16 | |
| | | | | C _L = 150 pF | | 14 | 38 | | 48 | | 57 | |

6.9 Operating Characteristics

T_A = 25°C

| PARAMETER | | TEST CONDITIONS | | TYP | UNIT |
|-----------------|--|-----------------|--|-----|------|
| C _{pd} | Power dissipation capacitance per buffer or driver | No load | | 40 | pF |

6.10 Typical Characteristics

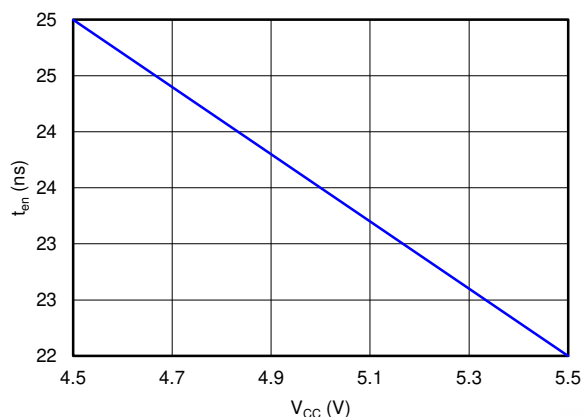
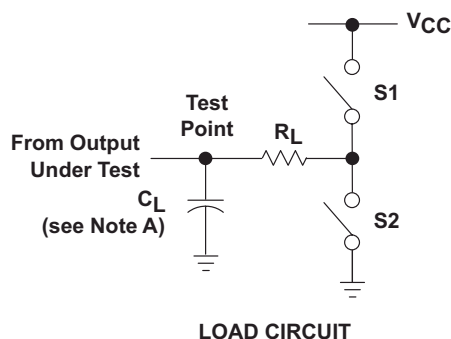
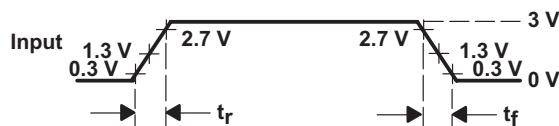


Figure 6-1. Enable Time vs V_{CC}

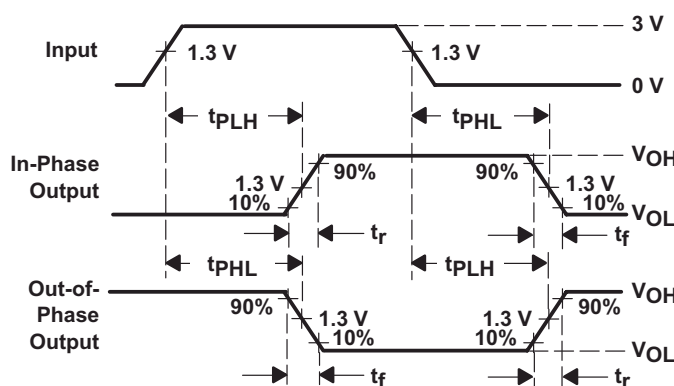
7 Parameter Measurement Information



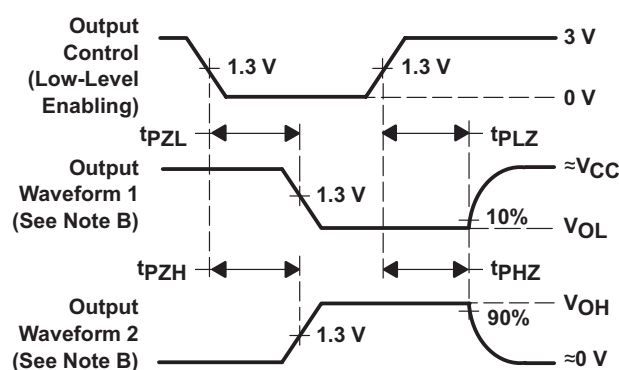
| PARAMETER | R_L | C_L | S1 | S2 |
|-------------------|--------------|-----------------|--------|--------|
| t_{en} | 1 k Ω | 50 pF or 150 pF | Open | Closed |
| | | | Closed | Open |
| t_{dis} | 1 k Ω | 50 pF | Open | Closed |
| | | | Closed | Open |
| t_{pd} or t_t | — | 50 pF or 150 pF | Open | Open |



VOLTAGE WAVEFORM
INPUT RISE AND FALL TIMES



VOLTAGE WAVEFORMS
PROPAGATION DELAY AND OUTPUT RISE AND FALL TIMES



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES FOR 3-STATE OUTPUTS

- NOTES:
- C_L includes probe and test-fixture capacitance.
 - Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: $PRR \leq 1$ MHz, $Z_O = 50 \Omega$, $t_r = 6$ ns, $t_f = 6$ ns.
 - The outputs are measured one at a time with one input transition per measurement.
 - t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - t_{PZL} and t_{PZH} are the same as t_{en} .
 - t_{PLH} and t_{PHL} are the same as t_{pd} .

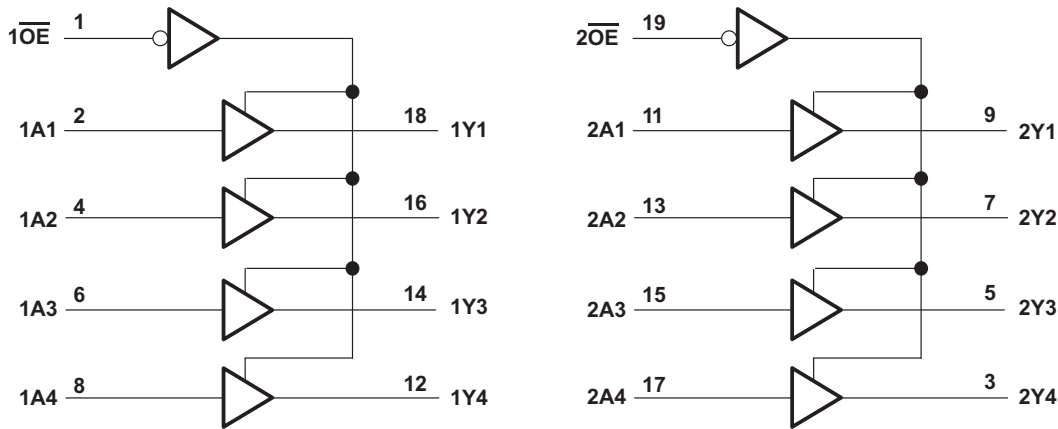
Figure 7-1. Load Circuit and Voltage Waveforms

8 Detailed Description

8.1 Overview

The SNx4HCT244 device is organized as two 4-bit buffers and line drivers with separate output-enable (\overline{OE}) inputs. When \overline{OE} is low, the device passes data from the A inputs to the Y outputs. When \overline{OE} is high, the outputs are in the high-impedance state. For the high-impedance state during power up or power down, \overline{OE} must be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

8.2 Functional Block Diagram



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Figure 8-1. Logic Diagram (Positive Logic)

8.3 Feature Description

The SN74HCT244 device can drive up to 15 LSTTL loads. This device has low power consumption of 80- μ A I_{CC} . The SN74HCT244 also has 3 state outputs that allow the outputs to go to high impedance, low or high.

8.4 Device Functional Modes

Table 8-1 lists the functions of the SNx4HC244.

Table 8-1. Function Table

| INPUTS | | OUTPUT Y |
|-----------------|---|-------------|
| \overline{OE} | A | |
| L | H | H |
| L | L | L |
| H | X | Z |

9 Application and Implementation

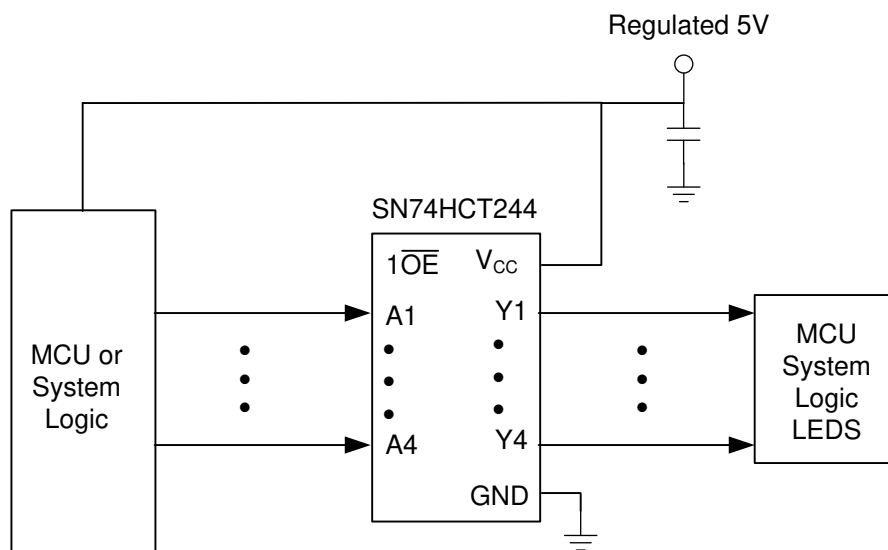
Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

9.1 Application Information

The SN74HC244 is a high-drive CMOS device that can be used for a multitude of bus interface type applications where output drive or PCB trace length is a concern.

9.2 Typical Application



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Figure 9-1. Application Schematic

9.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Avoid bus contention because it can drive currents in excess of maximum limits. The high drive creates fast edges into light loads, so consider routing and load conditions to prevent ringing.

9.2.2 Detailed Design Procedure

- Recommended input conditions:
 - For rise time and fall time specifications, see $\Delta t/\Delta V$ in [Recommended Operating Conditions](#).
 - For specified high and low levels, see V_{IH} and V_{IL} in [Recommended Operating Conditions](#).
- Recommend output conditions:
 - Load currents must not exceed the I_O maximum per output and must not exceed the continuous current through V_{CC} or GND total current for the part. These limits are located in [Absolute Maximum Ratings](#).
 - Outputs must not be pulled above V_{CC} .

9.2.3 Application Curve

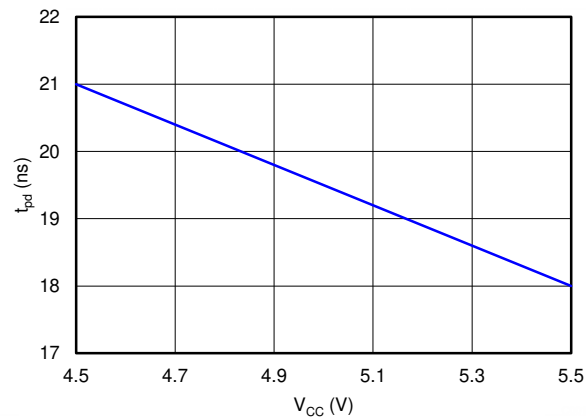


Figure 9-2. Propagation Delay vs V_{CC}

9.3 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in [Recommended Operating Conditions](#).

Each V_{CC} terminal must have a good bypass capacitor to prevent power disturbance. For devices with a single supply, TI recommends a 0.1-μF capacitor. If there are multiple V_{CC} terminals, then TI recommends 0.01-μF or 0.022-μF capacitors for each power terminal. It is okay to parallel multiple bypass capacitors to reject different frequencies of noise. Multiple bypass capacitors may be paralleled to reject different frequencies of noise. The bypass capacitor must be installed as close to the power terminal as possible for the best results.

9.4 Layout

9.4.1 Layout Guidelines

When using multiple bit logic devices, inputs must not float. In many cases, functions or parts of functions of digital logic devices are unused. Some examples are when only two inputs of a triple-input and gate are used, or when only 3 of the 4-buffer gates are used. Such input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states.

Specified in [Figure 9-3](#) are rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally they are tied to GND or V_{CC}, whichever makes more sense or is more convenient.

9.4.2 Layout Example

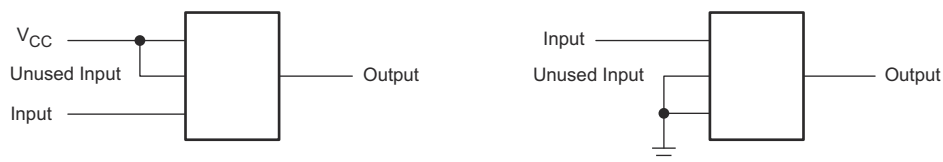


Figure 9-3. Layout Diagram

10 Device and Documentation Support

10.1 Documentation Support

10.1.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, [Implications of Slow or Floating CMOS Inputs](#)

10.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](#). Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

10.3 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

10.4 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

10.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

10.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|--------------------|------|----------------|---------------------|--------------------------------------|----------------------|--------------|-------------------------------------|-------------------------|
| 5962-8513001VRA | ACTIVE | CDIP | J | 20 | 20 | Non-RoHS & Green | SNPB | N / A for Pkg Type | -55 to 125 | 5962-8513001VR A SNV54HCT244J | Samples |
| 5962-8513001VSA | ACTIVE | CFP | W | 20 | 25 | Non-RoHS & Green | SNPB | N / A for Pkg Type | -55 to 125 | 5962-8513001VS A SNV54HCT244W | Samples |
| 85130012A | ACTIVE | LCCC | FK | 20 | 55 | Non-RoHS & Green | SNPB | N / A for Pkg Type | -55 to 125 | 85130012A SNJ54HCT 244FK | Samples |
| 8513001RA | ACTIVE | CDIP | J | 20 | 20 | Non-RoHS & Green | SNPB | N / A for Pkg Type | -55 to 125 | 8513001RA SNJ54HCT244J | Samples |
| JM38510/65755B2A | ACTIVE | LCCC | FK | 20 | 55 | Non-RoHS & Green | SNPB | N / A for Pkg Type | -55 to 125 | JM38510/ 65755B2A | Samples |
| JM38510/65755BRA | ACTIVE | CDIP | J | 20 | 20 | Non-RoHS & Green | SNPB | N / A for Pkg Type | -55 to 125 | JM38510/ 65755BRA | Samples |
| M38510/65755B2A | ACTIVE | LCCC | FK | 20 | 55 | Non-RoHS & Green | SNPB | N / A for Pkg Type | -55 to 125 | JM38510/ 65755B2A | Samples |
| M38510/65755BRA | ACTIVE | CDIP | J | 20 | 20 | Non-RoHS & Green | SNPB | N / A for Pkg Type | -55 to 125 | JM38510/ 65755BRA | Samples |
| SN54HCT244J | ACTIVE | CDIP | J | 20 | 20 | Non-RoHS & Green | SNPB | N / A for Pkg Type | -55 to 125 | SN54HCT244J | Samples |
| SN74HCT244DBR | ACTIVE | SSOP | DB | 20 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | HT244 | Samples |
| SN74HCT244DGSR | ACTIVE | VSSOP | DGS | 20 | 5000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | HT244 | Samples |
| SN74HCT244DWR | ACTIVE | SOIC | DW | 20 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | HCT244 | Samples |
| SN74HCT244DWRE4 | ACTIVE | SOIC | DW | 20 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | HCT244 | Samples |
| SN74HCT244DWRG4 | ACTIVE | SOIC | DW | 20 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | HCT244 | Samples |
| SN74HCT244N | ACTIVE | PDIP | N | 20 | 20 | RoHS & Green | NIPDAU | N / A for Pkg Type | -40 to 85 | SN74HCT244N | Samples |
| SN74HCT244NE4 | ACTIVE | PDIP | N | 20 | 20 | RoHS & Green | NIPDAU | N / A for Pkg Type | -40 to 85 | SN74HCT244N | Samples |
| SN74HCT244NSR | ACTIVE | SO | NS | 20 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 85 | HCT244 | Samples |

| Orderable Device | Status (1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan (2) | Lead finish/ Ball material (6) | MSL Peak Temp (3) | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|---------------|--------------|--------------------|------|----------------|-------------------------|--------------------------------------|----------------------|--------------|--------------------------------|-------------------------|
| SN74HCT244PWR | ACTIVE | TSSOP | PW | 20 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | HT244 | Samples |
| SN74HCT244PWRG4 | ACTIVE | TSSOP | PW | 20 | 2000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | -40 to 125 | HT244 | Samples |
| SNJ54HCT244FK | ACTIVE | LCCC | FK | 20 | 55 | Non-RoHS & Green | SNPB | N / A for Pkg Type | -55 to 125 | 85130012A SNJ54HCT 244FK | Samples |
| SNJ54HCT244J | ACTIVE | CDIP | J | 20 | 20 | Non-RoHS & Non-Green | SNPB | N / A for Pkg Type | -55 to 125 | 8513001RA SNJ54HCT244J | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN54HCT244, SN54HCT244-SP, SN74HCT244 :

- Catalog : [SN74HCT244](#), [SN54HCT244](#)
- Automotive : [SN74HCT244-Q1](#), [SN74HCT244-Q1](#)
- Enhanced Product : [SN74HCT244-EP](#), [SN74HCT244-EP](#)
- Military : [SN54HCT244](#)
- Space : [SN54HCT244-SP](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product - Supports Defense, Aerospace and Medical Applications
- Military - QML certified for Military and Defense Applications
- Space - Radiation tolerant, ceramic packaging and qualified for use in Space-based application

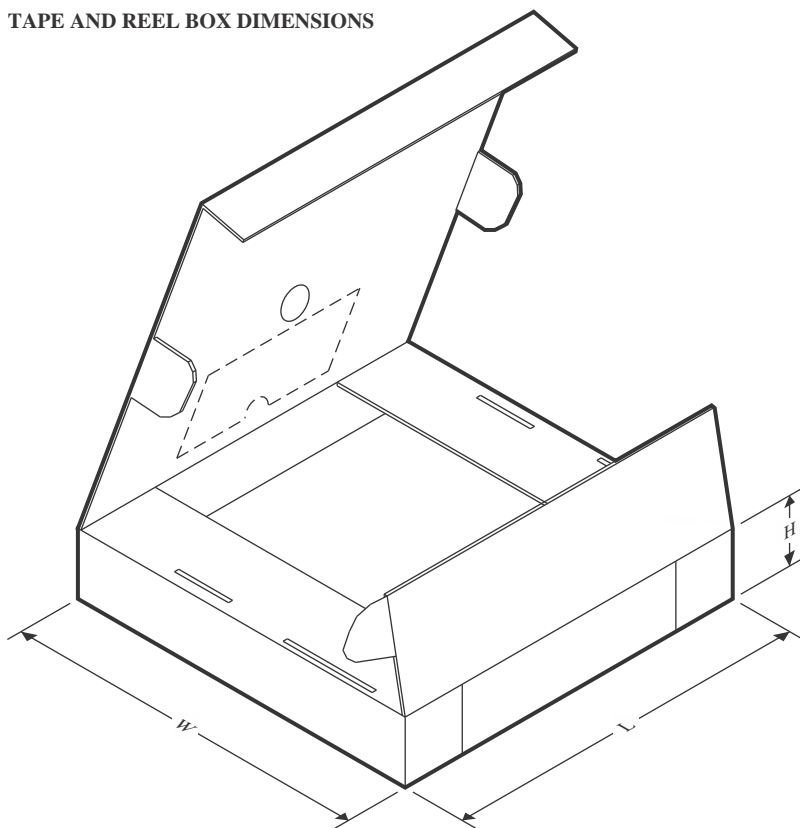
TAPE AND REEL INFORMATION



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|-----------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| SN74HCT244DBR | SSOP | DB | 20 | 2000 | 330.0 | 16.4 | 8.2 | 7.5 | 2.5 | 12.0 | 16.0 | Q1 |
| SN74HCT244DBR | SSOP | DB | 20 | 2000 | 330.0 | 16.4 | 8.2 | 7.5 | 2.5 | 12.0 | 16.0 | Q1 |
| SN74HCT244DGSR | VSSOP | DGS | 20 | 5000 | 330.0 | 16.4 | 5.4 | 5.4 | 1.45 | 8.0 | 16.0 | Q1 |
| SN74HCT244DWR | SOIC | DW | 20 | 2000 | 330.0 | 24.4 | 10.9 | 13.3 | 2.7 | 12.0 | 24.0 | Q1 |
| SN74HCT244DWR | SOIC | DW | 20 | 2000 | 330.0 | 24.4 | 10.9 | 13.3 | 2.7 | 12.0 | 24.0 | Q1 |
| SN74HCT244NSR | SO | NS | 20 | 2000 | 330.0 | 24.4 | 8.4 | 13.0 | 2.5 | 12.0 | 24.0 | Q1 |
| SN74HCT244NSR | SO | NS | 20 | 2000 | 330.0 | 24.4 | 8.4 | 13.0 | 2.5 | 12.0 | 24.0 | Q1 |
| SN74HCT244PWR | TSSOP | PW | 20 | 2000 | 330.0 | 16.4 | 6.95 | 7.0 | 1.4 | 8.0 | 16.0 | Q1 |
| SN74HCT244PWR | TSSOP | PW | 20 | 2000 | 330.0 | 16.4 | 6.95 | 7.0 | 1.4 | 8.0 | 16.0 | Q1 |
| SN74HCT244PWRG4 | TSSOP | PW | 20 | 2000 | 330.0 | 16.4 | 6.95 | 7.0 | 1.4 | 8.0 | 16.0 | Q1 |
| SN74HCT244PWRG4 | TSSOP | PW | 20 | 2000 | 330.0 | 16.4 | 6.95 | 7.0 | 1.4 | 8.0 | 16.0 | Q1 |

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

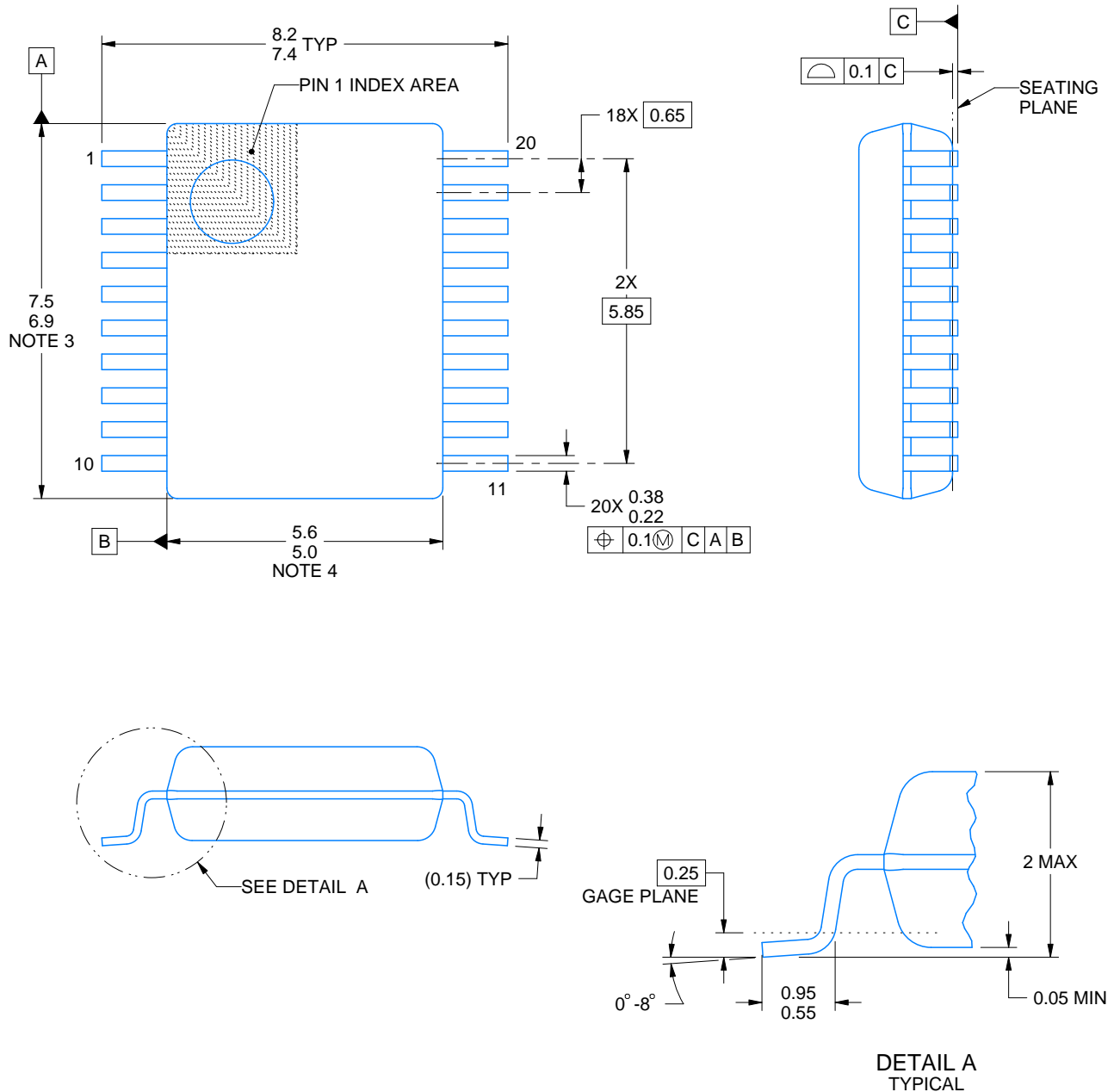
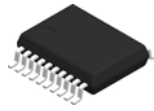
| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|-----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| SN74HCT244DBR | SSOP | DB | 20 | 2000 | 356.0 | 356.0 | 35.0 |
| SN74HCT244DBR | SSOP | DB | 20 | 2000 | 356.0 | 356.0 | 35.0 |
| SN74HCT244DGSR | VSSOP | DGS | 20 | 5000 | 356.0 | 356.0 | 35.0 |
| SN74HCT244DWR | SOIC | DW | 20 | 2000 | 356.0 | 356.0 | 41.0 |
| SN74HCT244DWR | SOIC | DW | 20 | 2000 | 367.0 | 367.0 | 45.0 |
| SN74HCT244NSR | SO | NS | 20 | 2000 | 367.0 | 367.0 | 45.0 |
| SN74HCT244NSR | SO | NS | 20 | 2000 | 367.0 | 367.0 | 45.0 |
| SN74HCT244PWR | TSSOP | PW | 20 | 2000 | 356.0 | 356.0 | 35.0 |
| SN74HCT244PWR | TSSOP | PW | 20 | 2000 | 356.0 | 356.0 | 35.0 |
| SN74HCT244PWRG4 | TSSOP | PW | 20 | 2000 | 356.0 | 356.0 | 35.0 |
| SN74HCT244PWRG4 | TSSOP | PW | 20 | 2000 | 356.0 | 356.0 | 35.0 |

TUBE



*All dimensions are nominal

| Device | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (μm) | B (mm) |
|------------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| 5962-8513001VSA | W | CFP | 20 | 25 | 506.98 | 26.16 | 6220 | NA |
| 85130012A | FK | LCCC | 20 | 55 | 506.98 | 12.06 | 2030 | NA |
| JM38510/65755B2A | FK | LCCC | 20 | 55 | 506.98 | 12.06 | 2030 | NA |
| M38510/65755B2A | FK | LCCC | 20 | 55 | 506.98 | 12.06 | 2030 | NA |
| SN74HCT244N | N | PDIP | 20 | 20 | 506 | 13.97 | 11230 | 4.32 |
| SN74HCT244NE4 | N | PDIP | 20 | 20 | 506 | 13.97 | 11230 | 4.32 |
| SNJ54HCT244FK | FK | LCCC | 20 | 55 | 506.98 | 12.06 | 2030 | NA |



4214851/B 08/2019

NOTES:

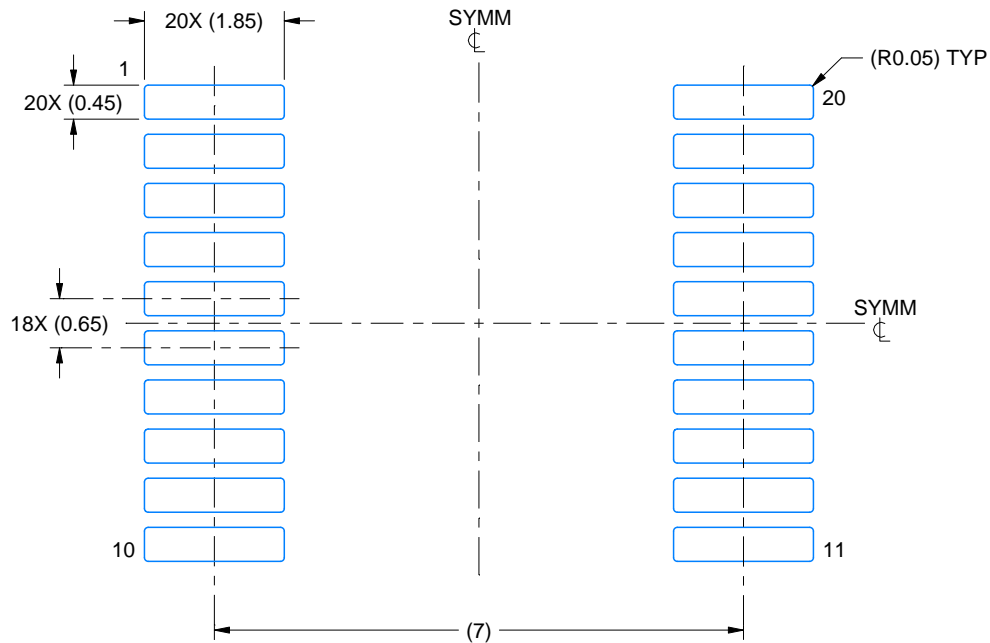
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-150.

EXAMPLE BOARD LAYOUT

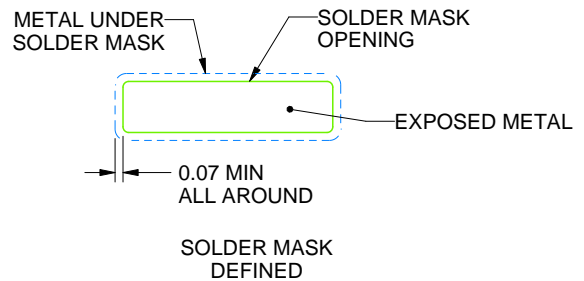
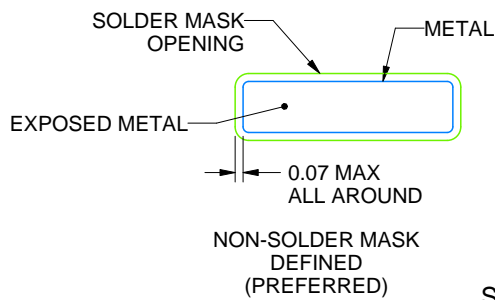
DB0020A

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



SOLDER MASK DETAILS

4214851/B 08/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

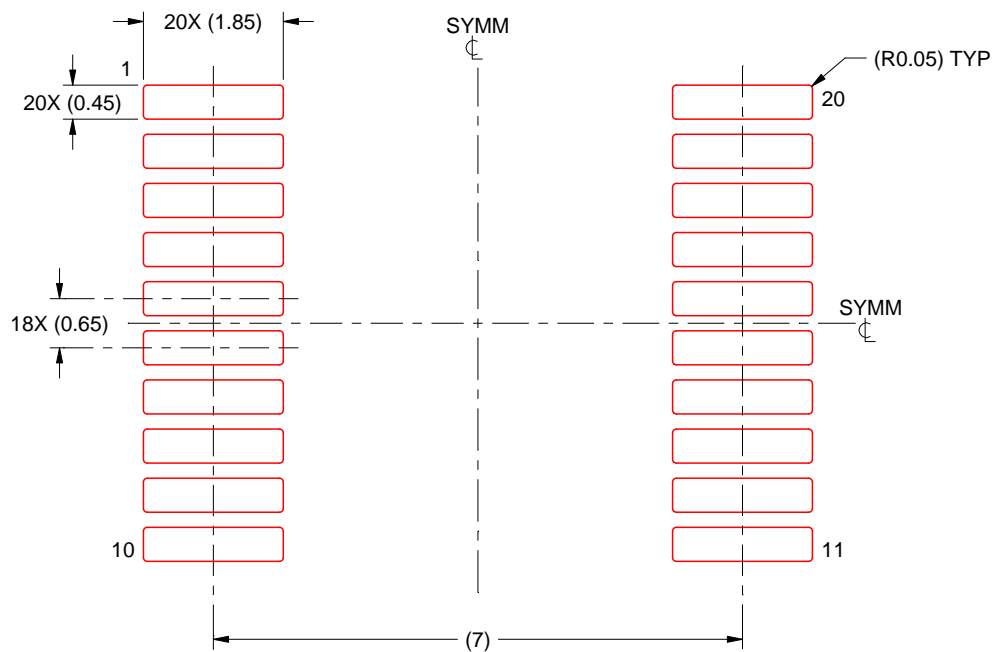
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DB0020A

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4214851/B 08/2019

NOTES: (continued)

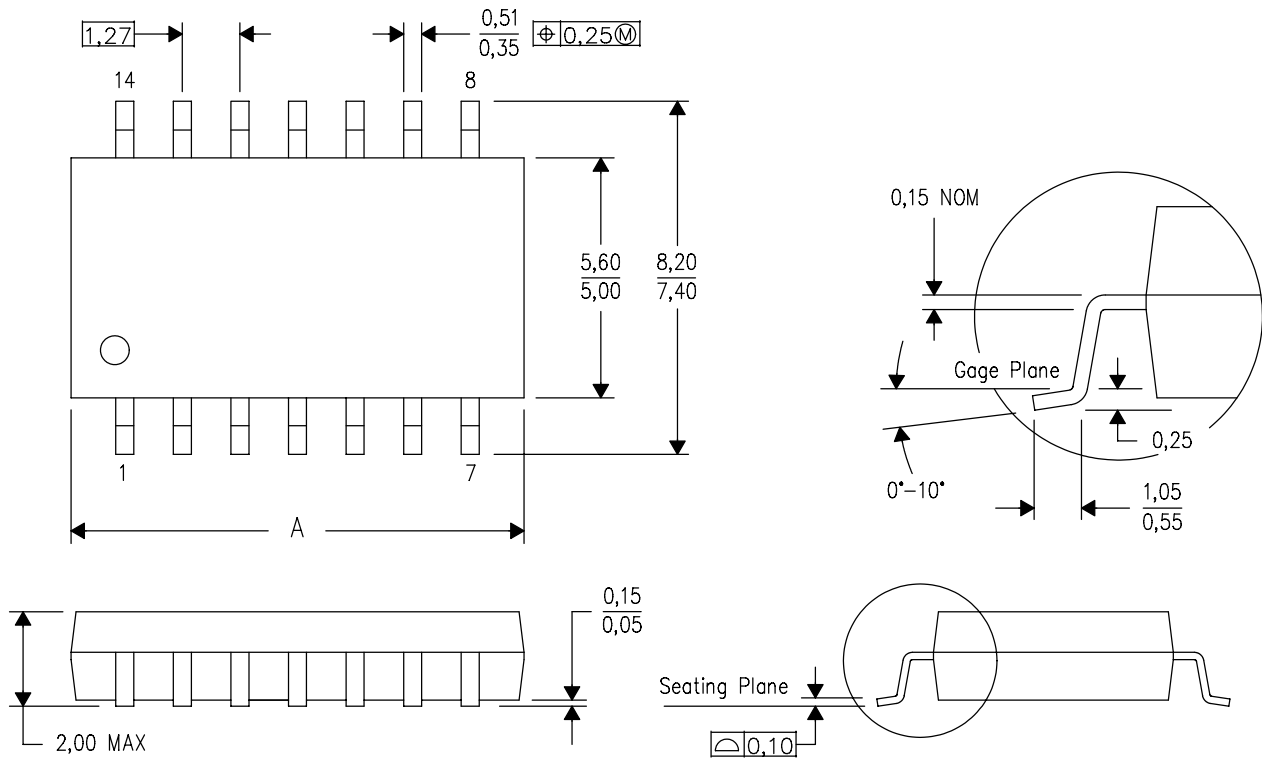
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

MECHANICAL DATA

NS (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14-PINS SHOWN



| DIM \ PINS ** | 14 | 16 | 20 | 24 |
|---------------|-------|-------|-------|-------|
| A MAX | 10,50 | 10,50 | 12,90 | 15,30 |
| A MIN | 9,90 | 9,90 | 12,30 | 14,70 |

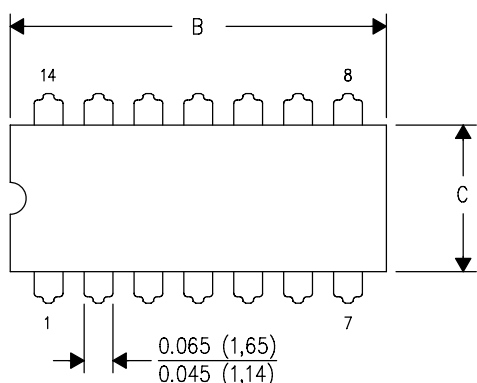
4040062/C 03/03

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

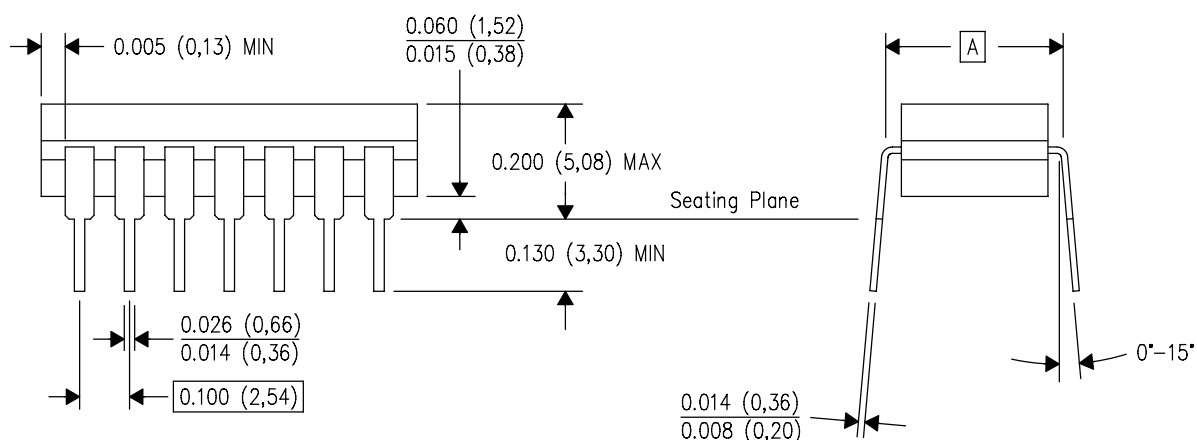
J (R-GDIP-T**)

14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



| PINS ** DIM | 14 | 16 | 18 | 20 |
|----------------|------------------------|------------------------|------------------------|------------------------|
| A | 0.300 (7,62) BSC | 0.300 (7,62) BSC | 0.300 (7,62) BSC | 0.300 (7,62) BSC |
| B MAX | 0.785 (19,94) | .840 (21,34) | 0.960 (24,38) | 1.060 (26,92) |
| B MIN | — | — | — | — |
| C MAX | 0.300 (7,62) | 0.300 (7,62) | 0.310 (7,87) | 0.300 (7,62) |
| C MIN | 0.245 (6,22) | 0.245 (6,22) | 0.220 (5,59) | 0.245 (6,22) |



4040083/F 03/03

- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package is hermetically sealed with a ceramic lid using glass frit.
 - D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
 - E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

GENERIC PACKAGE VIEW

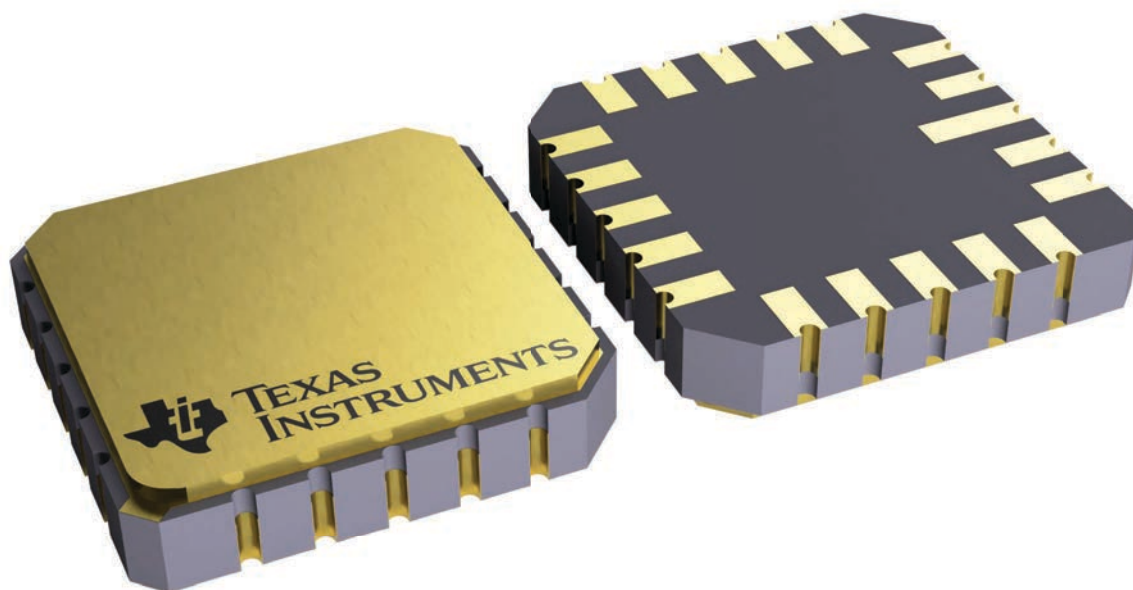
FK 20

LCCC - 2.03 mm max height

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

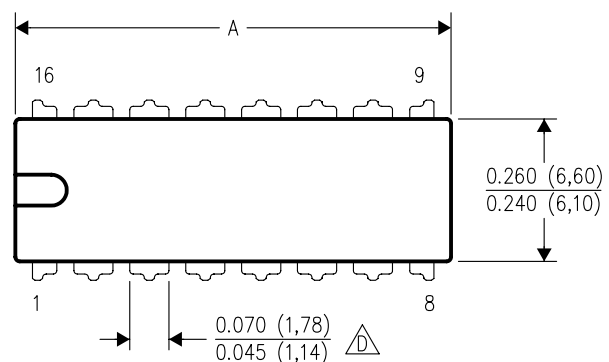


4229370VA\

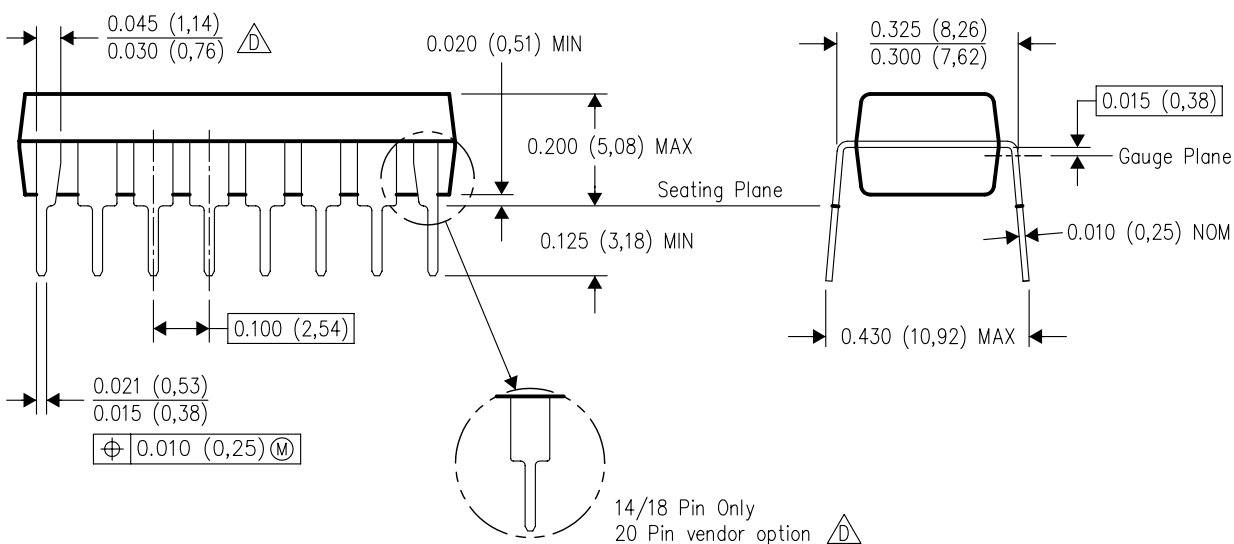
N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE





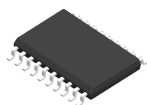
| PINS ** DIM | 14 | 16 | 18 | 20 |
|---------------------|------------------|------------------|------------------|------------------|
| A MAX | 0.775 (19,69) | 0.775 (19,69) | 0.920 (23,37) | 1.060 (26,92) |
| A MIN | 0.745 (18,92) | 0.745 (18,92) | 0.850 (21,59) | 0.940 (23,88) |
| MS-001 VARIATION | AA | BB | AC | AD |



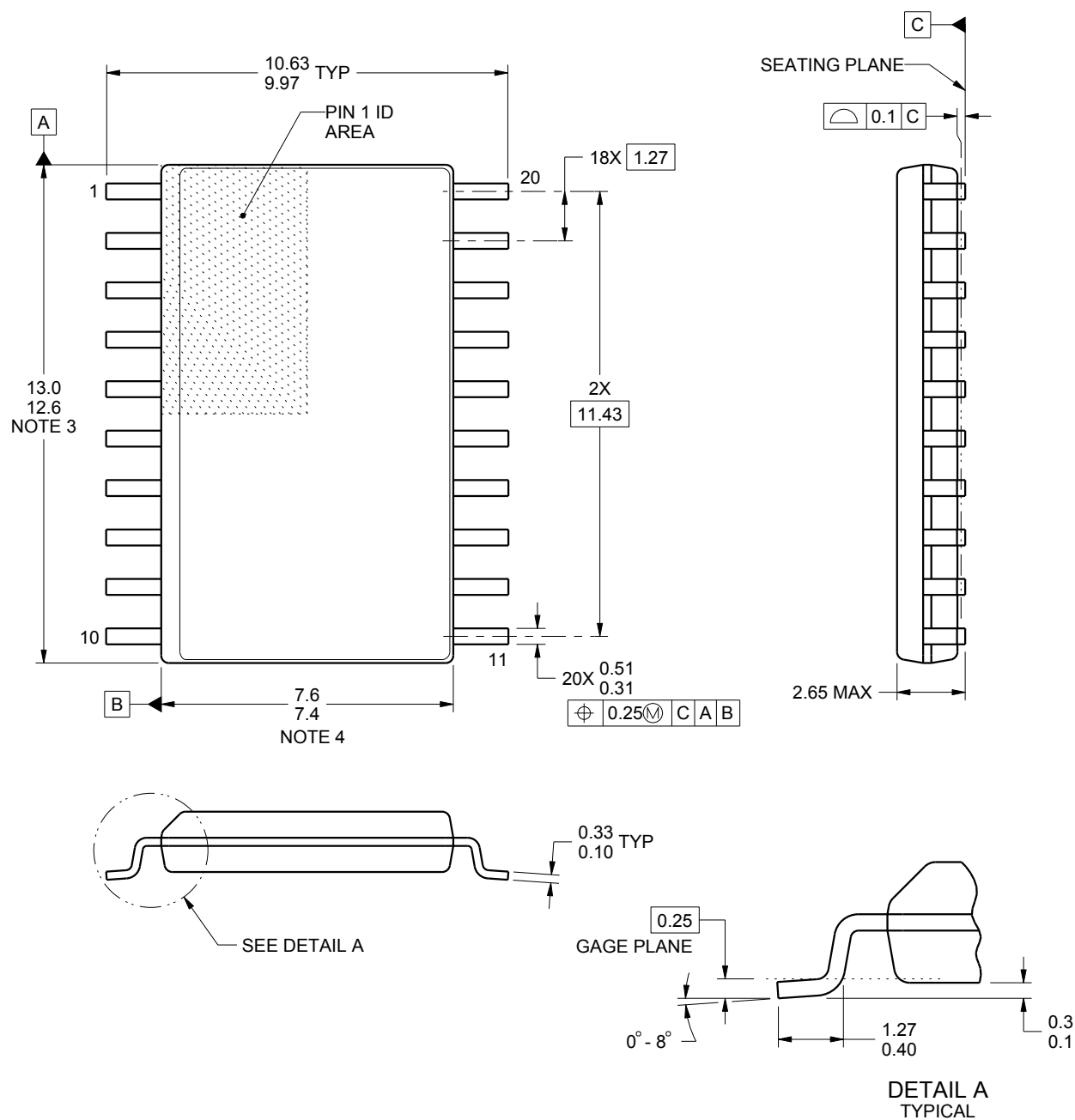
4040049/E 12/2002

NOTES:

- A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
-  Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 The 20 pin end lead shoulder width is a vendor option, either half or full width.

DW0020A**PACKAGE OUTLINE****SOIC - 2.65 mm max height**

SOIC



4220724/A 05/2016

NOTES:

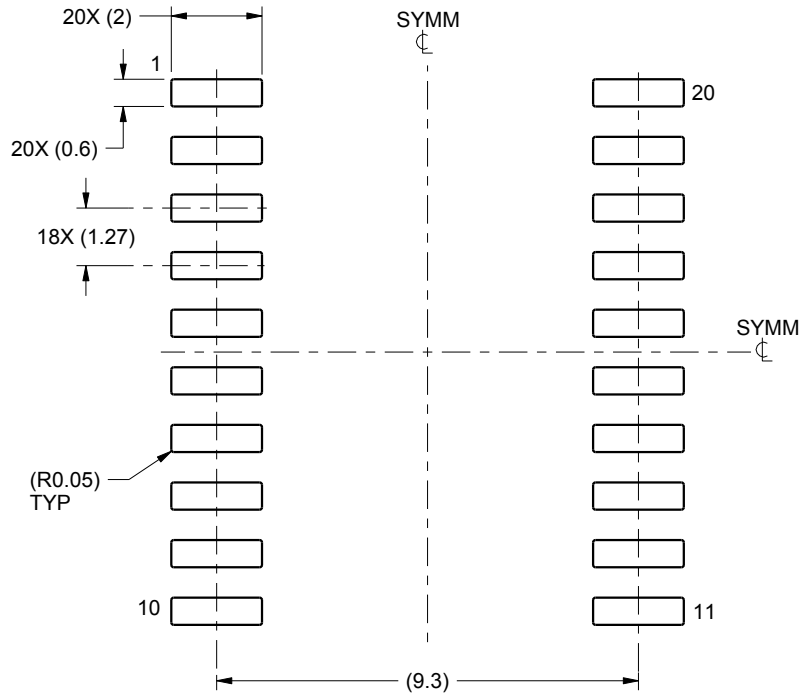
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
5. Reference JEDEC registration MS-013.

EXAMPLE BOARD LAYOUT

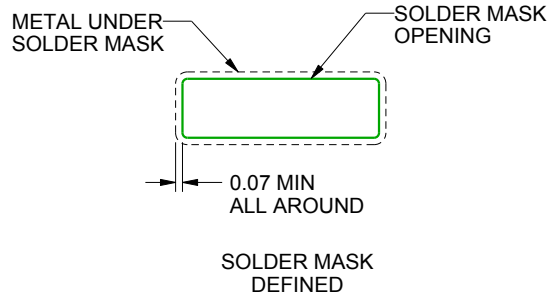
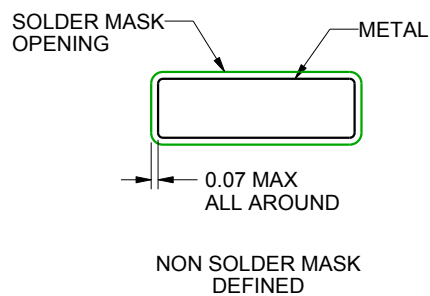
DW0020A

SOIC - 2.65 mm max height

SOIC



LAND PATTERN EXAMPLE
SCALE:6X



SOLDER MASK DETAILS

4220724/A 05/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

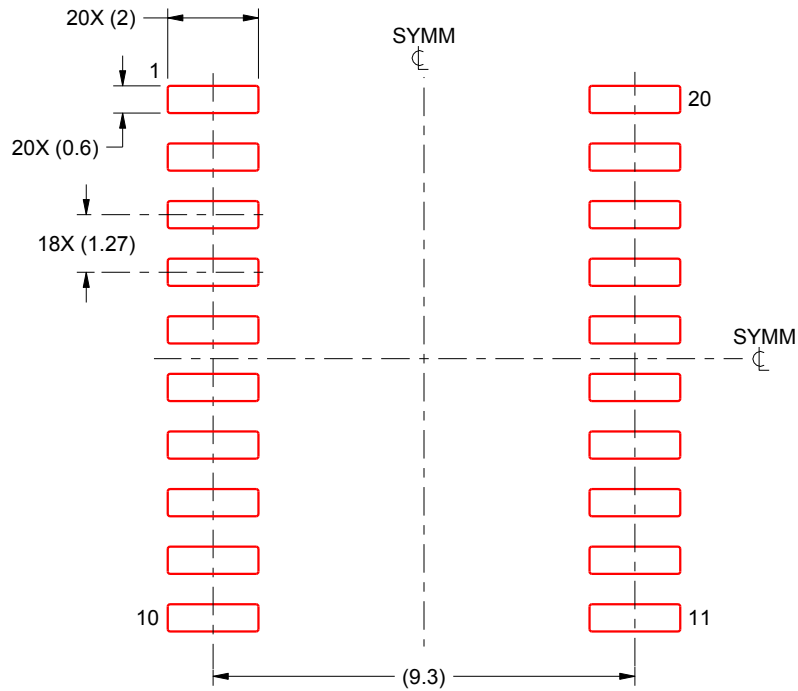
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DW0020A

SOIC - 2.65 mm max height

SOIC



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:6X

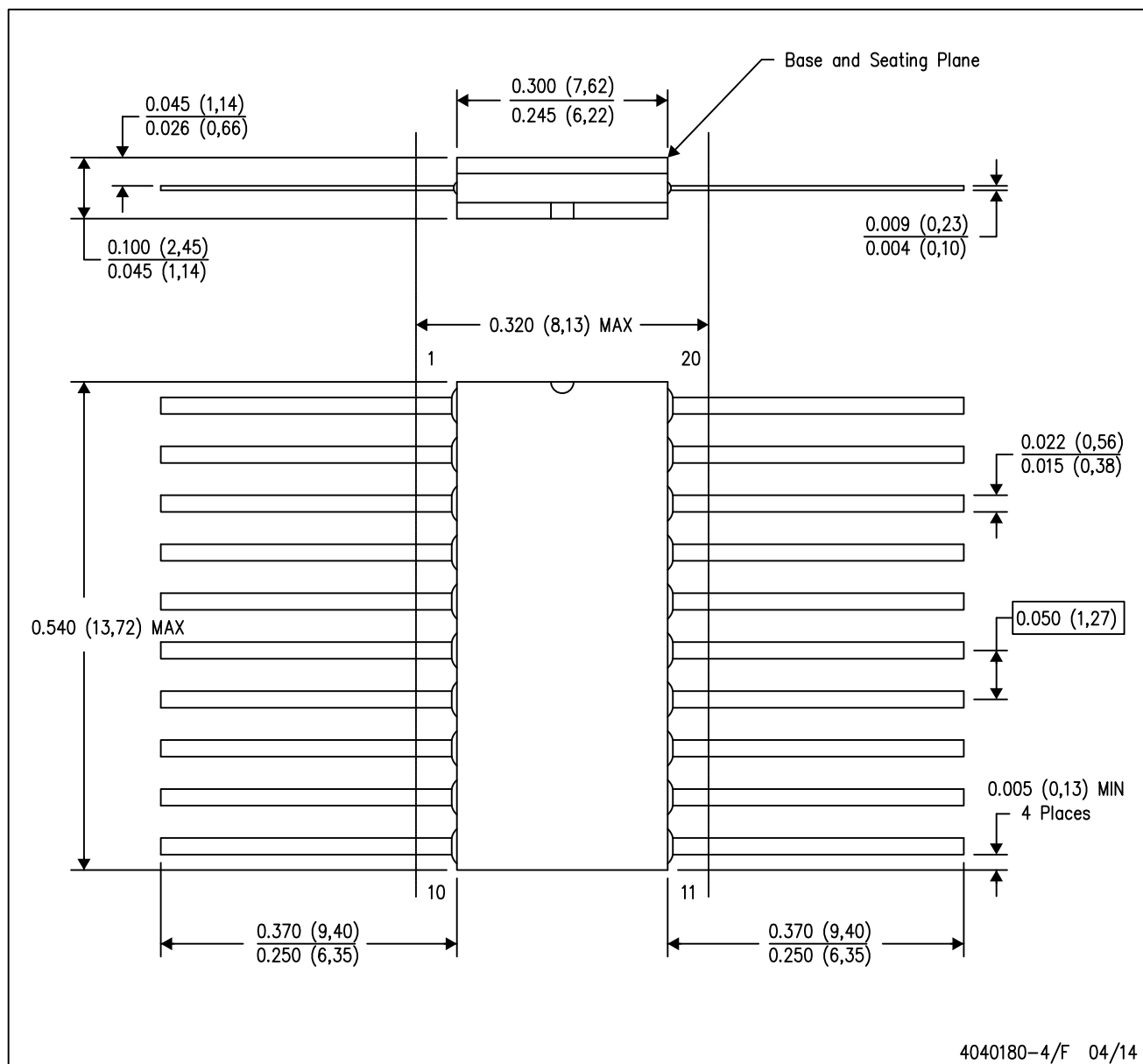
4220724/A 05/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

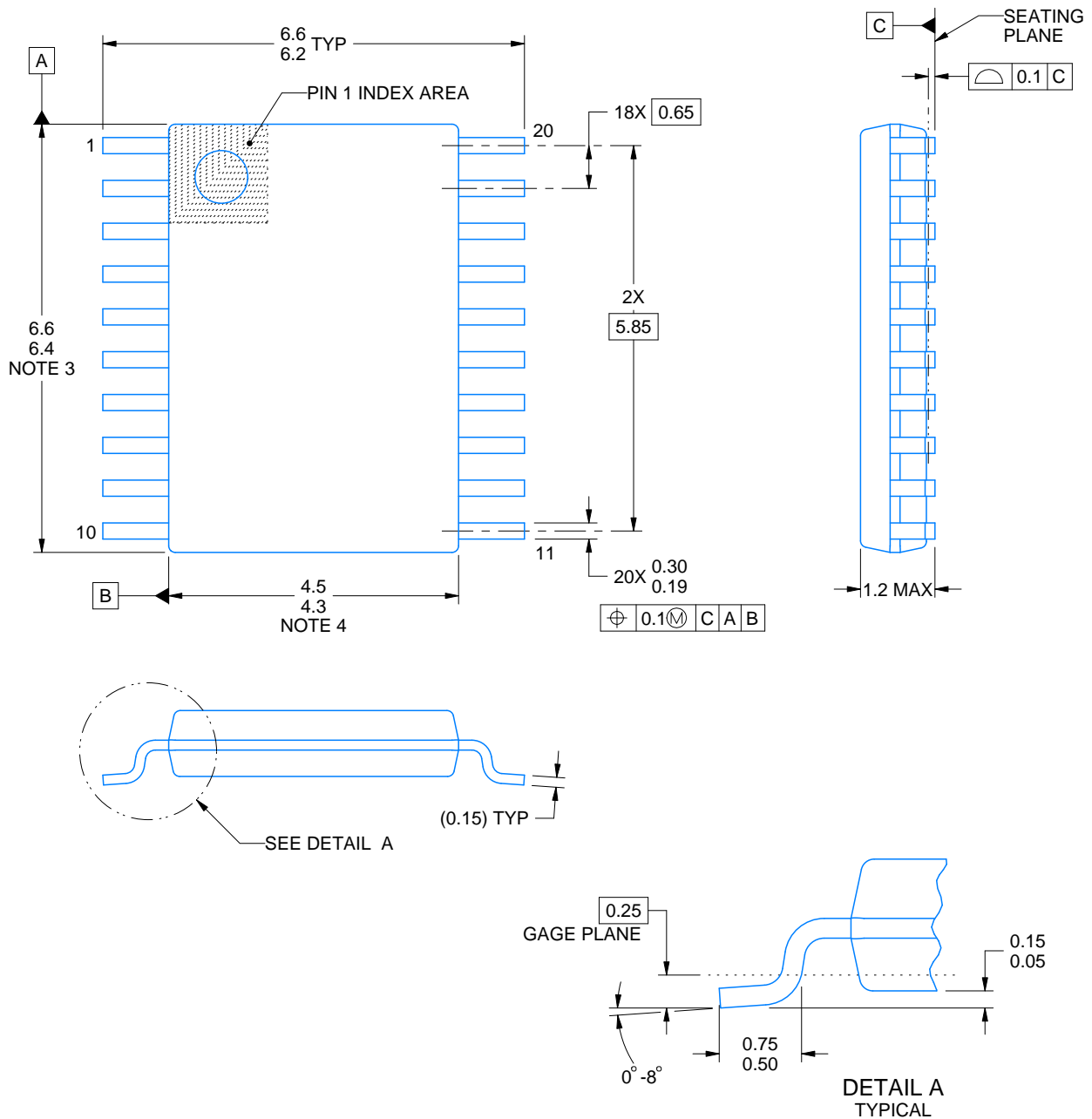
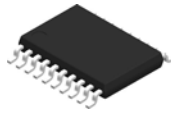
W (R-GDFP-F20)

CERAMIC DUAL FLATPACK



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within Mil-Std 1835 GDFP2-F20



4220206/A 02/2017

NOTES:

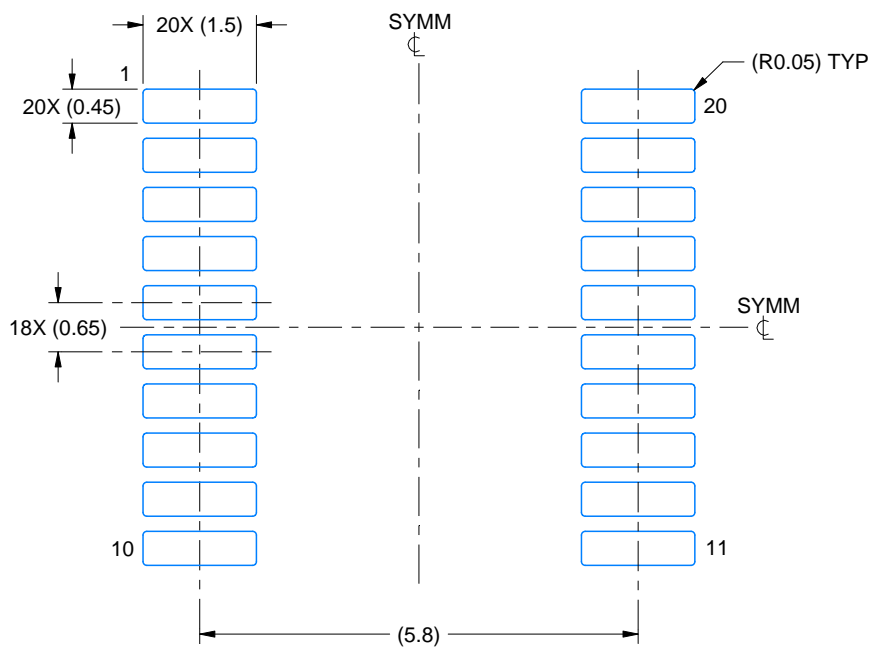
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-153.

EXAMPLE BOARD LAYOUT

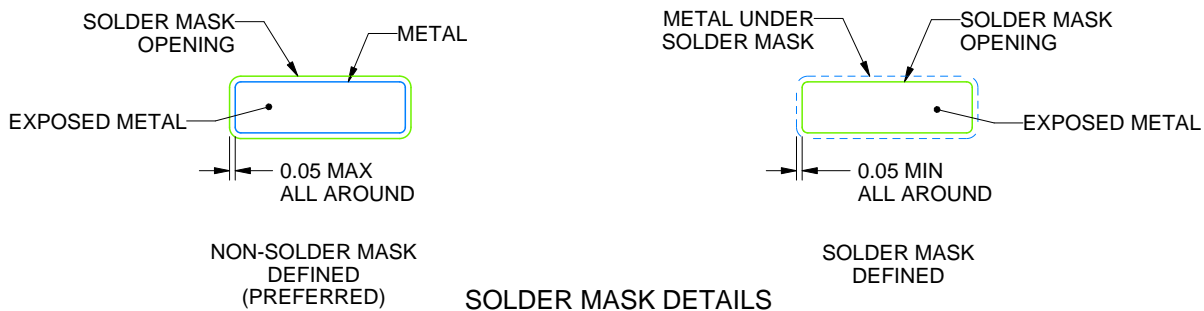
PW0020A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



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NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

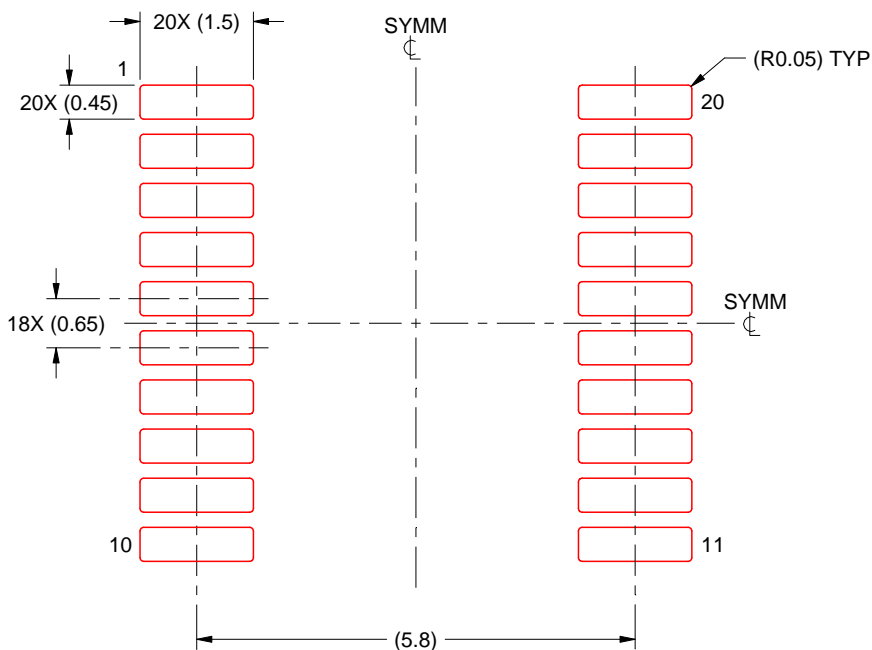
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0020A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

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NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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